Monolithic Linear IC

# LA7583

# IF Signal Processing Circuit (A<sup>2</sup>C PLL VIF + SIF) for TVs and VCRs

## Overview

The LA7583 is a VIF + SIF IC that requires no adjustments. In order to eliminate the need for adjustments in the VIF block, a multi-network PLL has been developed and adopted for video detection. In the SIF block, adjustments were eliminated by using gyrator technology in the FM quadrature detector. In addition to eliminating the need for adjustments, a buzz canceller that suppresses Nyquist buzz has been built into the LA7583 in order to provide excellent sound quality.

# Features

- Elimination of VCO, AFT, and SIF coils eliminates the need for adjustments.
- A variety of built-in filters.
- Built-in buzz canceller results in excellent audio characteristics.

Note: A<sup>2</sup>C Automatic Adjustment Control AQT Automatic Quadrature Tuning

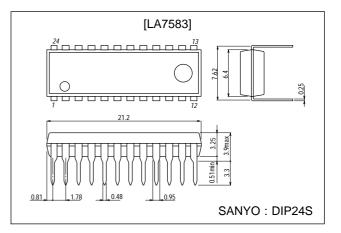
# Functions

[VIF] • Multinetwork PLL • VIF amplifier • Equalizer amplifier • AFT • AGC lag lead filter · Video driver [1st SIF] Preamplifier 1st SIF detector [SIF] • Limiter amplifier • AQT detector (gyrator) [mute] • AV mute · Audio mute

## **Package Dimensions**

unit : mm

### 3067-DIP24S



• BNC

- IFAGC
- AGC detector
- J/U switch
- FAGC
- Buzz canceller
- Built-in AGC filter

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# **Specifications**

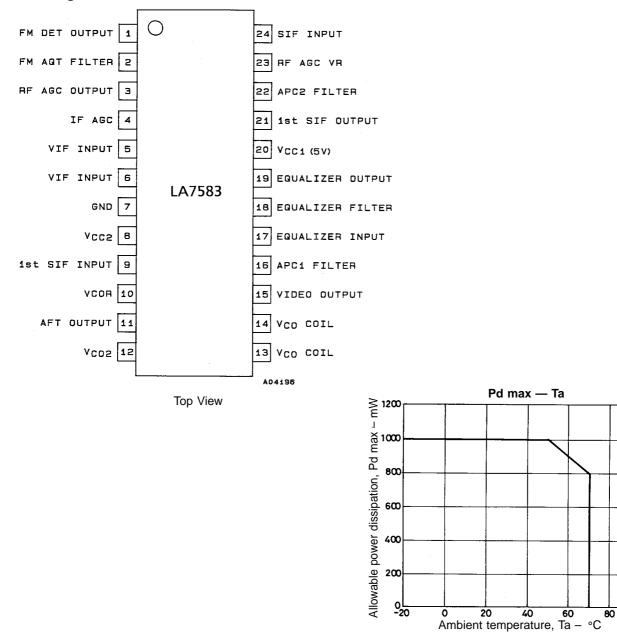
## Maximum Ratings at Ta = $25 \circ C$

Parameter	Symbol	Conditions	Ratings	Unit
	V <sub>CC</sub> 1		7	V
Maximum supply voltage	V <sub>CC</sub> 2		13.2	V
Circuit voltage	V4		V <sub>CC</sub> 1	V
Circuit voltage	V3, V11		V <sub>CC</sub> 2	V
Circuit current	I1, I10, I23		-1	mA
	I3, I21		-3	mA
	I15, I19		-5	mA
Allowable power dissipation	Pd max	$T_a \leq 50 \ ^{\circ}C$	1000	mW
Operating temperature	Topr		-20 to +70	°C
Storage temperature	Tstg		-55 to +150	°C

\* A<sup>2</sup>C (Automatic Adjustment Control)

Note: Current flowing into the IC is positive (no signal) and current flowing out is negative.

#### **Pin Assignment**



100

## Operating Conditions at Ta = $25 \,^{\circ}C$

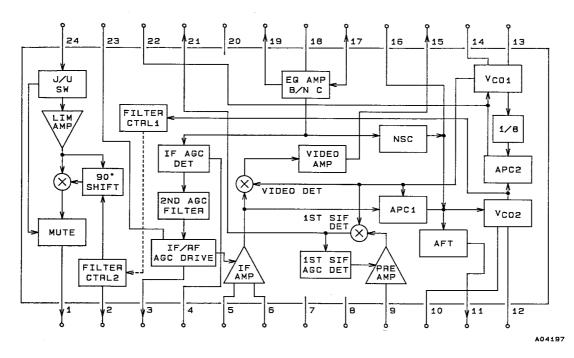
Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V <sub>CC</sub> 1		5	V
Recommended supply voltage	V <sub>CC</sub> 2		9	V
Operating supply voltage range	V <sub>CC</sub> 1		4.6 to 6	V
Operating supply voltage range	V <sub>CC</sub> 2		7 to 12	V

# Electrical Characteristics at Ta = 25 °C, $V_{\rm CC}1$ = 5 V, $V_{\rm CC}2$ = 9 V, fp = 45.75 MHz

Parameter	Symbol	Conditions	min	typ	max	Unit
[VIF Block]			L.			
Circuit current 1	120	$V_{CC} = 5 V$	57	66	78	mA
Circuit current 2	18	$V_{CC} = 9 V$	7.8	11.0	14.0	mA
Maxinum RF AGC voltage	V3H	V4 = 3 V	7.5	8.1	9	V
Mininum RF AGC voltage	V3L	V4 = 1.5 V		0	+0.5	V
Input sensitivity	Vi	S1 = OFF	32	38	44	dBµ
AGC range	G <sub>R</sub>		56	62		dB
Maxinum Allowable Input	Vi max		95	103		dBµ
Video output voltage with no signal	V19	V4 = 2 V	3.3	3.6	3.9	V
Sync signal tip voltage	V19(tip)	Vi = 10 mV	1.1	1.4	1.7	V
Video output amplitude	V <sub>O</sub> (V)	87.5% mod	1.7	2.0	2.3	Vp-p
Black noise threshold level voltage	V <sub>BTH</sub>		0.4	0.7	1.1	V
Black noise clamp voltage	V <sub>BCL</sub>		1.65	1.95	2.25	V
Output S/N	S/N		48	52		dB
920 kHz beat level	1920	P = 0, C = -10 dB, S = -10 dB	41	45		dB
Frequency characteristics	f <sub>C</sub>	P = 0, S = -14  dB	6	8		MHz
Differential gain	DG	Vi = 10 mV, 87.5%		3	8	%
Differential phase	DP	10STAR STEP		3	8	rad
AFT output voltage with no signal	V11		0.3	4.5	8.7	V
Maxinum AFT output voltage	V11H		7.5	8.5	9	V
Mininum AFT output voltage	V11L		0	+1	+1.5	V
AFT detection sensitivity	Sf		33	48	69	mV/kHz
VIF input resistance	Ri(VIF)	f = 45.75 MHz	0.8	1.1	1.5	kΩ
VIF input capacity	Ci(VIF)	f = 45.75 MHz	2	3	5	pF
APC pull-in range (U)	f <sub>PU</sub>		1.0	3		MHz
APC pull-in range (L)	f <sub>PL</sub>			-4.5	-1.0	MHz
AFT crossover frequency	Δf <sub>A</sub>		-65		+65	kHz
VCO1 movimum voriable range	∆f <sub>U</sub> 1	V22 = 4 V	2.0	5.0		MHz
VCO1 maximum variable range	$\Delta f_L 1$	V22 = 2 V		-5.0	-2.0	MHz
	∆f <sub>U</sub> 2	V16 = 4 V	100	200		kHz
VCO2 maximum variable range	$\Delta f_L 2$	V16 = 2 V		-1000	-200	kHz
VCO1 control sensitivity	β1	V22 = 2.8 V to 3.2 V	2.4	4.8	9.6	kHz/mV
VCO2 control sensitivity	β2	V16 = 2.8 V to 3.2 V	0.3	0.6	1.2	kHz/mV
[1st SIF Block]			•			
4.5 MHz output gain	VG	Vi = 1 mV, 41.25 MHz	23	26	29	dB
4.5 MHz output level	SO	Vi = 10 mV, 41.25 MHz	50	85	120	mVrms
1st SIF maximum input level	Si (max)	So + 12 dB – 1 dB	60	70		mVrms
1st SIF input resistance	Ri (SIF1)	f = 41.25 MHz	1.2	2		kΩ
1st SIF input capacity	Ci (SIF1)	f = 41.25 MHz		3	6	pF

Parameter	Symbol	Conditions	min	typ	max	Unit
[SIF Block]		•				
SIF limiting sensitivity	Vi (lim)	Δf = 25 kHz, 400 Hz	47	53	59	dBµ
FM detection output voltage	Vo	Vi = 100 mV, ∆f = 25 kHz, 400 Hz	300	400	520	mVrms
AMR	AMR	AM = 30%, 400 Hz	40	56		dB
Total harmonic distortion	THD	Δf = 25 kHz, 400 Hz		0.4	1.5	%
SIF S/N	S/N(SIF)	Δf = 25 kHz, 400 Hz	55	59		dB
[Mute defeat]						
FM mute	V24T		0.5	1.0		V
AFT defeat voltage	VD11		3.9	4.5	5.1	V
J/U SW start voltage	VJU24		1.5	2.0	2.5	V
AV mute voltage	VM23		1	1.5		V

#### **Equivalent Circuit Block Diagram**



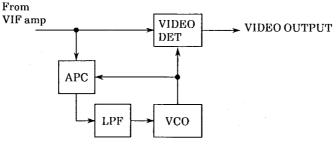
### Multinetwork PLL (Automatic Adjustment Control)

The LA7583's PIF detector uses a multinetwork PLL and a buzz canceller. The multinetwork PLL is a PLL detector that was developed in order to eliminate the need for adjustments in video detection.

This PLL detector offers the following features:

- (1) Eliminates the need for adjustments in video detection.
- (2) The PLL detection characteristics are unaltered.
  - a. Offers better waveform response characteristics in comparison with the quasi-synchronous detection method.
  - b. The harmonic wave component of the video signal (demodulated output) is reduced.
  - c. The 1/2 IF signal suppression ratio is improved.
- (3) Audio buzz is greatly reduced by the buzz canceller.

A typical PLL detector consists of the blocks shown below.

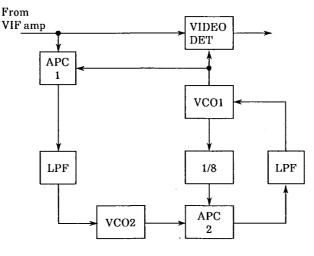


#### (PLL DETECTOR)

In these blocks, if the VCO coil is not adjusted to the IF frequency, a phase difference will appear in the control loop. As a result, the PLL detector detection axis will shift from the ideal  $180^{\circ}$ . The group delay, DP characteristics, etc., deteriorate as a result.

[Multinetwork PLL]

The multinetwork PLL consists of the blocks shown below.



#### (MULTI NETWORK PLL)

The multinetwork PLL has two VCO circuits. Each of these form a separate PLL. The operational relationship between these circuits is as follows:

 $f_{VCO1} = f_{VCO2} \times 8$ 

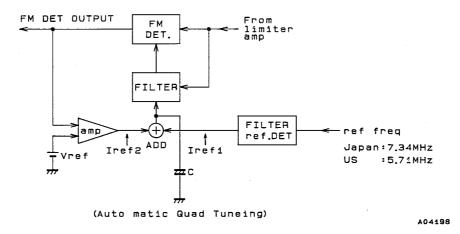
Initially, in APC1, the phases of the IF signal and the VCO carrier are compared. The control signal derived is then used to control VCO2. VCO1 is controlled by comparing the phases of VCO2 and VCO1 x 1/8. As a result, VCO1 always has the same frequency as the IF signal, and the following relationship results:

 $f_{VCO1} = f_{VCO2} \times 8$ 

If the precision of the ceramic oscillator for  $f_{VCO2}$  is within the adjustment range for VCO in a typical PLL, the video detector phase error is very small. As a result, the multinetwork PLL operates as an ideal PLL detector.

#### Automatic Quadrature Tuning (AQT)

A quadrature detector that is controlled automatically is used in the FM detector. The AQT in the LA7583 consists of the blocks shown in the following diagram.



The FM detection filter (gyrator) is controlled at 4.5 MHz by the control current (Iref1) generated by reference circuit 1. At the same time, precision control is performed by using the control current (Iref2) derived by detecting the offset from the detected output so that the FM detector phase relationship is 90 °. As a result, automatic control makes an ideal quadrature detector possible.

#### (Note) Gyrator: Circuit-formed equivalent inductance

The SIF circuit contains a 4.5 MHz tank circuit having the gyrator and an internal capacitor.

## **Pin Functions**

Pin No.	Symbol	Circuit Configuration	Description
1	FM DETECTOR OUTPUT	AUDIO DUT PUT UT PUT DEEMPHASIS	<ul> <li>Pin 1 is an audio FM output pin. A 100 Ω resistor is connected in series with the emitter follower.</li> <li>(1) Monaural applications CR are used to form a de-emphasis cicuit externally. t = CR1</li> <li>(2) Audio multiplexing applications Depending on the audio multiplexing decoder application, the input impedance is low, which may distort the L-R signals, etc., and degrade the stereo characteristics. In such an event, add a resistor between pin 1 and GND. R2 ≥ 5.1 kΩ</li> </ul>
2	FM AQT FILTER	VCC1 VCC1	Pin 2 is the FM Automatic Quadrature Tuning filter pin. This pin controls the quadrature detector so that it remains at its center frequency (4.5 MHz), and is the point where the two control currents are added. If the value of external capacitor C1 is small, the low-range frequency characteristics deteriorate. If the capacitance is too large, the low-range characteristics at SW-ON, etc., worsen. The recommended value for C1 is 10 $\mu$ F to 33 $\mu$ F.
3	RF AGC OUTPUT	$ \begin{array}{c}                                     $	Pin 3 is the RF AGC output pin. It is an emitter output, and a protective resistor of $200 \Omega$ is connected between pin 3 and emitter. This pin determines the resistance bleeder (R1, R2) values according to the maximum gain of the tuner.

Pin No.	Symbol	Circuit Configuration	Description
4	IF AGC	$H_{1} = C_{1}$ $(1)$ $(1)$ $(1)$ $(1)$ $(2)$ $(1)$	Pin 4 is the 1st IFAGC filter pin. This filter smoothes out the peaks detected in the signal by the AGC detector, and generates the AGC voltage. The 2nd AGC filter (lag lead filter) is built in using filter technology. The cutoff frequency is approximately 500 Hz. • AGC filter constants and AGC speed Medium-speed AGC: R1 = 330 kΩ C1 = 0.1 $\mu$ F High-speed AGC: R1 = 470 kΩ C1 = 0.056 $\mu$ F
56	VIF INPUT	VIF IN SAN R $\neq$ 3L SAN	Pins 5 and 6 are the VIF amplifier input pins. The VIF amplifier has three stages, each of which uses a C cut, so when used in conjunction with a SAW filter, DC cut by a capacitor becomes unnecessary. Ri = $1.1 \text{ k}\Omega$ Ci = $3 \text{ pF}$
9	1st SIF INPUT	V2 V1 V2 V2 V2 V2 V2 V2 V2 V2 V2 V2	Pin 9 is the 1st SIF input pin. Input is such that DC cut must be performed using a capacitor. When a SAW filter, etc. is used in the input circuit, an L that is used to neutralize the SAW filter output capacitance and the IC input capacitance serves to improve the 1st SIF sensitivity.

Pin No.	Symbol	Circuit Configuration	Description
10	VCOR	$V_{CC1}$	Pin 10 is the pin for connecting the resistor that determines the impedance of the oscillation point of the oscillating circuit by the ceramic oscillator. Oscillation frequency variations can be reduced by connecting a resistor with a tolerance of 1% between pin 10 and pin 12.
11	AFT OUTPUT		Pin 11 is the AFT output pin. This pin
		AFT $AFT$ $AP$ $FT$ $AP$ $FT$ $FT$ $FT$ $FT$ $FT$ $FT$ $FT$ $FT$	determines the gain (control sensitivity: $\beta$ (kHz/mV)) according to the R1 and R2 bleeder resistance values. $\beta$ is decreased in weak electric fields by AGC voltage in order to reduce malfunction of AFT. R1 and R2 must be 200 k $\Omega$ or less. V AFT curve for medium/ strong electric fields AFT curve for weak electric fields IF fp
12	VCO2	VCC1	Pin 12 is the ceramic oscillator (VCO2) pin. A series resonance-type oscillator is used to oscillate 1/8 of the IF signal. Japan = 58.75 MHz × 1/8 U.S. = 45.75 MHz × 1/8
		777 A04205	

Pin No.	Symbol	Circuit Configuration	Description
13 14	VCO COIL		Pins 13 and 14 are the VCO tank circuit. VCO coil recommended • Japan 1.2 μH • U.S. 1.8 μH Make the circuit pattern between the IC and the coil as short as possible.
15	VIDEO OUTPUT	VCC1	Pin 15 is the SIF carrier (4.5 MHz)-contained video output pin. The level of the video output is approximately 1.5 Vp-p.
16	APC1 FILTER	$\begin{array}{c} \hline \\ \hline $	Pin 16 is the APC1 filter pin. The filter smoothes the output after comparing the phase of the IF signal with that of VCO1 in APC1. $C_1 = 0.47 \ \mu\text{F}$ $R_1 = 330 \ to 560\Omega$ $C_2 = 470 \ \text{pF}$

Pin No.	Symbol	Circuit Configuration	Description
17	EQUALIZER INPUT	EQ IN VIDEO WUTE 20ka T T A04211	<ul> <li>Pin 17 is the equalizer amplifier input pin. A signal which has passed through a 4.5 MHz trap is input through pin 17 and is output through pin 19.</li> <li>The input level of pin 17 is 1.5 Vp-p. This is amplified 3 dB to 2 Vp-p by the equalizer amplifier.</li> </ul>
18	EQUALIZER FILTER	VCC1 30ka R1 TO VIDEO DRIVERO 39.2ka 1ka JBIVERO 10 To VIDEO DRIVERO 10 To VIDEO DRIVERO	Pin 18 is the equalizer pin. The equalizer amplifier is of the voltage follower type with a voltage gain of 3 dB. To correct the frequency characteristics, connect LCR externally. The operating characteristics are as follows: $Av = \frac{Ve}{Vi} = 1 + \frac{R1}{Z}$ (times)
19	EQUALIZER OUTPUT	VCC1 HO HO HO HO HO HO HO HO HO HO HO HO HO	Pin 19 is the equalizer amplifier output pin. This output has a built-in low-impedance drive circuit.

21       1st SIFOUT       Fin 21 is the 1st SIF output pin. The SIF carrier output level is approximately so mVms.         22       APC2 FILTER       Fin 22 is the APC2 filter pin. The filter smoothes the output after comparing the phase of VC2 with that of VC01 x 1/8 in APC2.         23       RF AGC VR       Fin 23 is the RF AGC adjusting pin. The adjustment point is effected by droping this pin to GND.	Pin No.	Symbol	Circuit Configuration	Description
23 RF AGC VR 23 RF AGC VR F	21	1st SIFOUT	3ka 3ka 56.8ka 2000 2000 2000 1ST SIF BPF 2000 ₩ 1 1 1 1 1 1 1 1 1 1 1 1 1	carrier output level is approximately
adjustment point is where Rv approximates adjustment point is where Rv approximates 15 kΩ. AV (audio/video) mute is effected by dropping this pin to GND.	22	APC2 FILTER		smoothes the output after comparing the phase of VCO2 with that of VCO1 x $1/8$ in APC2.
A04217	23	RF AGC VR	V	adjustment point is where Rv approximates 15 k $\Omega$ . AV (audio/video) mute is effected by

Pin No.	Symbol	Circuit Configuration	Description
24	SIF INPUT, J/U SW	AUDIO AUDIO TO LIMITER TO LIMITER AND AUDIO AUDI	Pin 24 is used both for SIF input and J/U SW audio mute. • The input impedance is approximately 1.5 k $\Omega$ . • J/U (Japan/U.S.) switch The oscillating frequency for VCO2 in Japan and the U.S. differs. However, the center frequency of the SIF detector is controlled using VCO2 as a reference. As a result, the filter control mode can be changed either by leaving this pin open or dropping it to GND through a 3.9 k $\Omega$ resistor. Open: Japan mode $3.9 k\Omega$ : U.S. mode • Audio mute: Audio muting can be applied by dropping the voltage on this pin to 0.5 V or less.

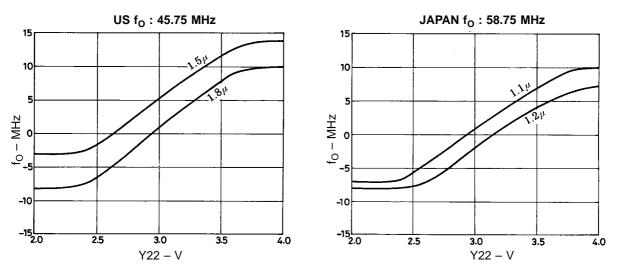
LA7583 VCO COIL design considerations

1. Design criteria

Allow for an adequate variable range for the IF frequency in the design. Specifically, select a coil value so that the carrier frequency is roughly in the center of the characteristics diagram shown below when 2 V and 4 V are applied to pin 22.

- 2. Design notes
  - a. When selecting the L value, the LA7583 must be soldered directly on the board. If an IC socket is used, an error in the VCO center frequency will arise from the capacitance of the socket.
  - b. The patterns for pins 13 and 14 must be made as short as possible (15 mm or less). Minimize the effect of the printed pattern.
  - c. A VCO coil of which tolerance is  $\pm$  5% must be used.
- 3. Measuring the IF frequency range

Drop the IF AGC (pin 4) to GND. Next, pick up the VCO carrier leak at a pin other than the VCO coil (pins 13 and 14) and read the carrier frequency. And then, apply a voltage ranging from 1.5 V to 4.5 V to pin 22, and record the characteristics of the maximum variable frequency range for VCO as shown in the diagram below.



4. Recommended VCO coil

A. Tokyo Parts Industry Co., Ltd. 5LC JAPAN 1.2  $\mu H \pm 5\%$  U.S. 1.8  $\mu H \pm 5\%$ 

Notes on Sanyo SAW Filters

There are two types of filters, depending on the piezoelectric substrate material.

(1) LiTaO<sub>3</sub> (lithium tantalate) SAW filters: ......TSF1xxx

TSF2xxx

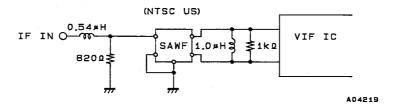
While the LiTaO<sub>3</sub> SAW filters offer excellent stability with a low temperature coefficient of -18 ppm/°C, the insertion loss is high. However, by using a coil, etc., to obtain proper matching on the SAW filter output side (which does increase the number of external components), it is possible to suppress the insertion loss while at the same time making the level of the characteristics variable, which provides additional design freedom. (Refer to Fig. 13.) In addition, because the SAW (surface wave) reflection is small, ripple within the band can be kept low.

#### (2) LiNbO3 (lithium niobate) SAW filter: ......TSF5xxx

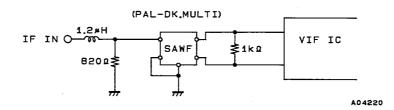
While the LiNbO<sub>3</sub> SAW filter has a high temperature coefficient of  $-72 \text{ ppm/}{}^{\circ}\text{C}$ , it has a lower insertion loss by about 10 dB compared to the LiTaO<sub>3</sub> SAW filters. Therefore, matching on the output side of the SAW filter is not necessary. (Refer to the diagram below.) In addition, because the insertion loss is low (although the ripple within the band is somewhat higher than in the case of the LiTaO<sub>3</sub> SAW filter), the low impedance and small feedthrough diminish the effects of peripheral circuit components and the pattern layout, and make it possible to stabilize the trap characteristics outside of the band.

From the above, it is clear that the  $LiTaO_3$  SAW filter is suitable for Japan and U.S. bands where the IF frequency is high, while the  $LiNbO_3$  SAW filter is suitable for PAL and U.S. bands where the IF frequency is low.

#### LiTaO<sub>3</sub> SAW Filter



LiNbO<sub>3</sub> SAW Filter

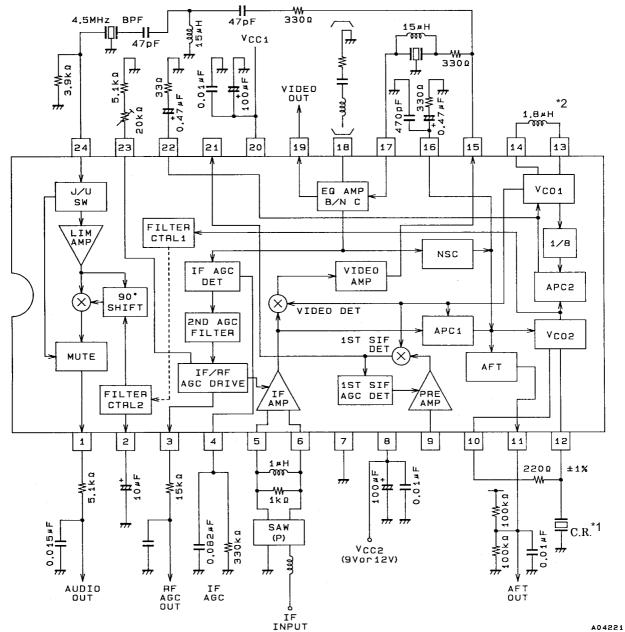


(a) Picture wide BAND SAW Filter Japan TSF1137U U.S. TSF1241U(with IS-31 Trap)

- (b) INTER Carrier SAW Filter
  - Japan TSF1138P
    - U.S. TSF1220P

## **Test circuit Diagram**

LA7583 (U.S.)



\*1. TDK ceramic oscillator FCR5.71M2SF3 \*2. Micro-inductor 5LC1R8, made by Tokyo Parts Industry Co., Ltd.

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